

Spécialité de Master « Optique, Matière, Plasmas »

Stage de recherche (4 mois minimum, à partir de début mars)

Proposition de stage (ne pas dépasser 1 page)

Date de la proposition :

Responsable du stage / internship supervisor:			
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Lieu du stage / internship place:	4 place Jussieu, 75005 Paris		

Titre du stage / Semiconductor quantum dots for the generation of non classical states of light
Résumé / summary
<p>Reliable single-photon sources are of great interest for applications in the emerging fields of quantum information processing, but also for fundamental quantum optics experiments. For instance, in quantum cryptography it is necessary to ensure a perfectly secure transmission of information and for this purpose, one needs a single-photon source able to emit on demand, one and only one photon. The simplest idea for realizing a single-photon source is to use the fluorescence of a two-level quantum system. The main practical challenge for achieving a high-performance single-photon source remains to increase the probability to detect a photon per excitation cycle. This probability depends both on the optical properties of the emitter and on the extraction efficiency of the optical device.</p> <p>The aim of this work is to address both of these issues from the fundamental point of view and propose an optimized optical device for single-photon sources applications. We propose to improve the emission properties of the source (high emission rate, high degree of coherence) as well as the light extraction efficiency by building new devices. Semiconductor quantum dots will be used as non-classical light sources for realizing quantum optics experiments. Single semiconductor quantum dots will be addressed and coherently manipulated <i>on resonance</i> in order to minimize decoherence processes due to interaction between the dot and its environment characteristic in solid state systems. Thus, the emitted photons will have a maximum degree of indistinguishability. New structures will be developed in order to enhance the spontaneous emission rate of the source while improving the source extraction efficiency. Entanglement of two quantum bits will be demonstrated either using independent photons emitted by a single dot or two photons each one emitted by independent quantum dots. The possibility of entangling two exciton states created in two independent quantum dots will also be investigated. The achievement of two qu-bits operations is an important and challenging task to accomplish towards the implementation of logic gates for quantum computation within the solid-state. Up to now, triggered independent sources of indistinguishable single photon are lacking.</p> <p>During this internship, the student will participate in the realization of the photons correlation setup for characterizing the coherence properties of the semiconductor quantum dots.</p>
Toutes les rubriques ci-dessous doivent obligatoirement être remplies

Ce stage pourra-t-il se prolonger en thèse ? Possibility of a PhD ? : oui			
Si oui, financement de thèse envisagé/ financial support for the PhD: ED			
Lasers et matière	x	Lumière, Matière : Mesures Extrêmes	x
Optique de la science à la technologie		Plasmas : de l'espace au laboratoire	

Fiche à transmettre (fichier pdf **obligatoirement**) sur le site <http://stages.master-omp.fr>